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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/807,364	03/23/2004	Han-Chung Lai	250122-1440	3950
24504	7590	08/08/2006	EXAMINER	
THOMAS, KAYDEN, HORSTEMEYER & RISLEY, LLP 100 GALLERIA PARKWAY, NW STE 1750 ATLANTA, GA 30339-5948				QI, ZHI QIANG
		ART UNIT		PAPER NUMBER
		2871		

DATE MAILED: 08/08/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)
	10/807,364	LAI, HAN-CHUNG
	Examiner Mike Qi	Art Unit 2871

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) Responsive to communication(s) filed on 14 June 2006.
 2a) This action is **FINAL**. 2b) This action is non-final.
 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) Claim(s) 1,4-6 and 10-14 is/are pending in the application.
 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
 5) Claim(s) _____ is/are allowed.
 6) Claim(s) 1,4-6 and 10-14 is/are rejected.
 7) Claim(s) _____ is/are objected to.
 8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) The specification is objected to by the Examiner.
 10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
 Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
 Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 a) All b) Some * c) None of:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ . |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____ . | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| | 6) <input type="checkbox"/> Other: _____ . |

DETAILED ACTION

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on June 14, 2006 has been entered.

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 11-14 are rejected under 35 U.S.C. 102(b) as being anticipated by US 6,310,668 B1 (Ukita).

Regarding claim 11, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that a liquid crystal display device with a capacitance-compensated structure comprises:

- first process layer comprising a gate line (33), a gate (32) and a compensation structure (such as 61), and the gate (32) is electrically connected to the gate line (33), and the compensation structure (such as 61) connects to the gate (32) (because the compensation structure such as 61 connected to the gate line 33 and the gate line 33 connected to the gate 32);

- second process layer comprising a data line (38), a source (39) (the drain electrode 39 functions also as source electrode) and a drain (42) (the protruded portion of the pixel electrode 42 functions also as drain electrode); and the source and the drain are formed corresponding to both side of the gate (32) respectively (see Fig.11); and the source (39) is electrically connected to the data line (38); and the data line (38) is substantially perpendicular to the gate line (33);
- there is an acceptable alignment shift range between the first process layer and the second process layer; because when a gate pattern (as first process) and a source pattern (as second process) are vertically or horizontally misaligned in a mask alignment process, would keep the parasitic capacitance between the gate and the source electrode (functions as drain electrode) at a constant value (see col.4, lines 41-52); such that the sum of the capacitance of the first parasitic capacitor between the first side of the drain and the gate and a second parasitic capacitor between the second side of the drain and the compensation structure maintain a substantially constant value within the acceptable alignment shift range.

Regarding claims 12, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that the capacitance-compensated structure extends from the gate line (such as 61).

Regarding claims 13, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that the capacitance-compensated structure extends from the gate (such as the protruded portion of the gate 32).

Regarding claim 14, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that the capacitance-compensated structure comprises two portions, wherein one portion extends from the gate line (such as 61) and the other portion extends from the gate (such as the protruded portion of the gate 32).

Claim Rejections - 35 USC § 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

4. Claims 1, 4-5 and 10 are rejected under 35 U.S.C. 103(a) as being unpatentable over US 6,310,668 B1 (Ukita) in view of US 7,075,595 (Moon).

Regarding claims 1 and 5, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that a liquid crystal display device with a capacitance-compensated structure comprises:

(concerning claim 1)

- gate line (33);
- gate (32) electrically connected to the gate line (33);
- compensation structure (such as 61 or a protruded portion of the gate electrode functions also as compensation structure) extending from at least one of the gate and gate line, i. e., extending from the gate (32) or the gate line (33);

- the protruded portion of the pixel electrode (42) functions as drain electrode having a first side (such as left side) opposite to a second side (such as right side), and the first side (left side) of the drain (42) overlaps the gate (32) and the second side (right side) of the drain (42) overlaps the compensation structure (such as 61);

(concerning claim 5)

- gate line (33) and data line (38) to turn the thin film transistor on or off;
- first parasitic capacitor is formed between the first side (left side) of the drain (42) and the gate (32) and a second parasitic capacitor is formed between the second side (right side) of the drain (42) and gate (32) (because the gate line 33 connected to the gate 32) (any two conductive electrodes create parasitic capacitors), and the second parasitic capacitor comprises the second side (right side) of the drain (42) and a compensation structure extending from at least one of the gate and gate line, i.e., the second side (right side) of the drain (42) and a compensation structure extending from the gate (32) or the gate line (33).

Ukita does not explicitly disclose that a pixel electrode disposed on a part of the drain and electrically connected to the drain through a via.

Moon teaches (col.8, line 40 – col. 9, line 13; Fig.8) that a pixel electrode (225) disposed on a part of the drain (117) and electrically connected to the drain (117) through a via (the drain contact hole 221). Because the pixel electrode and the drain electrode are formed in different layer through an insulating layer (such as 118), so that

the connection must be through a via (such as a contact hole 221). Moon further teaches (col.8, line 44 – col.9, line 14; Fig.8) that the both end sides of the drain electrode (117) overlap the gate electrode (a portion of the gate line 113 is used as the gate electrode as shown in Fig.8), and any misalignment occurring in the step of forming the drain electrode (117) is compensated. If the left portion “A1” of the overlapped area is decreased due to horizontal misalignment, the right portion “A2” is increased. Thus, the overlapped area between the drain electrode (117) and the gate electrode (115) is maintained uniformly even though misalignment occurs (see col.8, lines 53-63). Thus, the variation of the gate-drain parasitic capacitance is prevented, and flickering and the image retention are prevented (see col.9, lines 8 – 13).

Therefore, it would have been obvious to those skilled in the art at the time the invention was made to modify the capacitance-compensation structure of Ukita with the teachings of a pixel electrode disposed on a part of the drain and connected to the drain through a via and the both end sides of the drain overlap the gate electrode as taught by Moon, since the skilled in the art would be motivated for obtaining a capacitance-compensation structure having such pixel electrode and compensating any misalignment, and that is the same principles used as this application.

Regarding claims 4 and 10, Ukita discloses (col.4, line 29 – col.6, line 21; Fig.11) that the capacitance-compensated structure comprises two portions, wherein one portion extends from the gate line (such as 61) and the other portion extends from the gate (such as the protruded portion of the gate 32).

5. Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ukita and Moon as applied to claims 1, 4-5 and 10 above, and further in view of US 5,995,178 (Fujikawa et al).

Regarding claim 6, Ukita teaches the invention set forth above except for that a capacitor dielectric layer of the first parasitic capacitor comprises two portions wherein one portion is a stacked structure comprising a gate insulating layer, a semiconductor layer and a channel protection layer, and the other portion is a stacked structure comprising the gate insulating layer and the semiconductor layer; a capacitor dielectric layer of the second parasitic capacitor is a stacked structure comprising the gate insulating layer and the semiconductor layer.

Fujikawa teaches (Fig.19) that a TFT structure comprises the gate insulating layer and the semiconductor layer and that is common and known in the art. The first and second parasitic capacitors of this application are between the drain electrode and the gate electrode and between the drain electrode and the compensation structure (extended from gate electrode and gate line). As shown in the Fig.19 of Fujikawa, such parasitic capacitor would cover two portions for the dielectric layer that is one portion having the gate insulating layer (422), semiconductor layer (423) and channel protection layer (424), and the other portion having the gate insulating layer (422), semiconductor layer (423). Therefore, the first parasitic capacitor comprises such two portions, the second parasitic capacitor is not at center portion so that the dielectric layer would comprise the gate insulating layer and the semiconductor layer. Such that the TFT

structure having gate insulating layer and semiconductor layer that is common and known in the art and Fujikawa as the evidence.

Concerning the TFT structure having channel protective layer, Fujikawa teaches (Fig.19) that the TFT structure having channel protection layer (424) functions as etching stopper so as to protect the channel portion during the etching process (see col.1, lines 57-65).

Therefore, it would have been obvious to those skilled in the art at the time the invention was made to modify the liquid crystal display of Ukita with the teachings of using the TFT structure having channel protective layer as taught by Fujikawa, since the skilled in the art would be motivated for protecting the channel portion of the TFT during the etching process (see col.1, lines 57-65).

Response to Arguments

6. Applicant's arguments with respect to claims 1, 4-6 and 10-14 have been considered but are moot in view of the new ground(s) of rejection.
7. In response to applicant's argument that the references fail to show certain features of applicant's invention, it is noted that the features upon which applicant relies (i.e., the pixel electrode and the drain line are not formed by the same layer as they are formed by material with different properties) are not recited in the rejected claim(s). Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See *In re Van Geuns*, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993).

Conclusion

8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.
9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Mike Qi whose telephone number is (571) 272-2299.

The examiner can normally be reached on M-T 8:00 am-5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.


Mike Qi
Patent examiner
Aug.4, 2006